

Appl. No. 10/026,470; Filed: December 27, 2001
Dkt. No. 1875.1350000; Group Art Unit: 2825
Inventors: Tam et al.; Tel.: (202) 371-2600
Title: A Thick Oxide P-Gate NMOS Capacitor for Use in a
Phase-Locked Loop Circuit and Method of Making Same

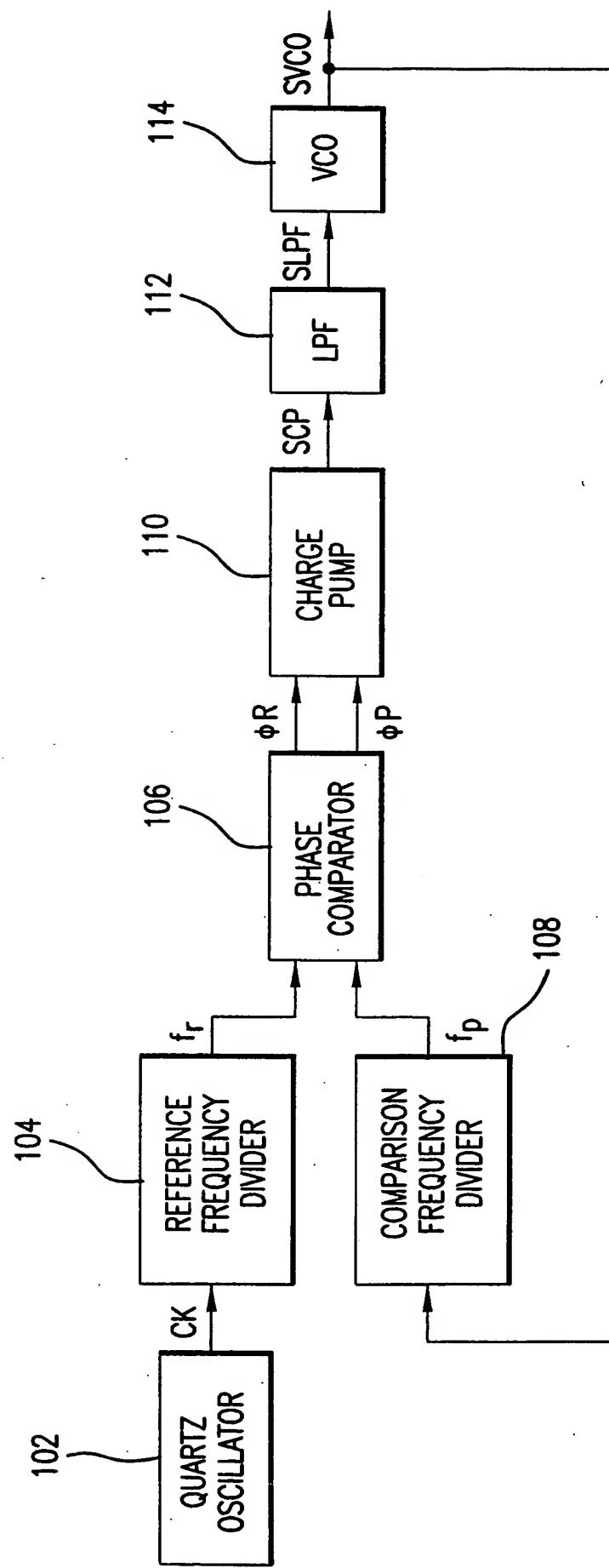


FIG. 1
PRIOR ART

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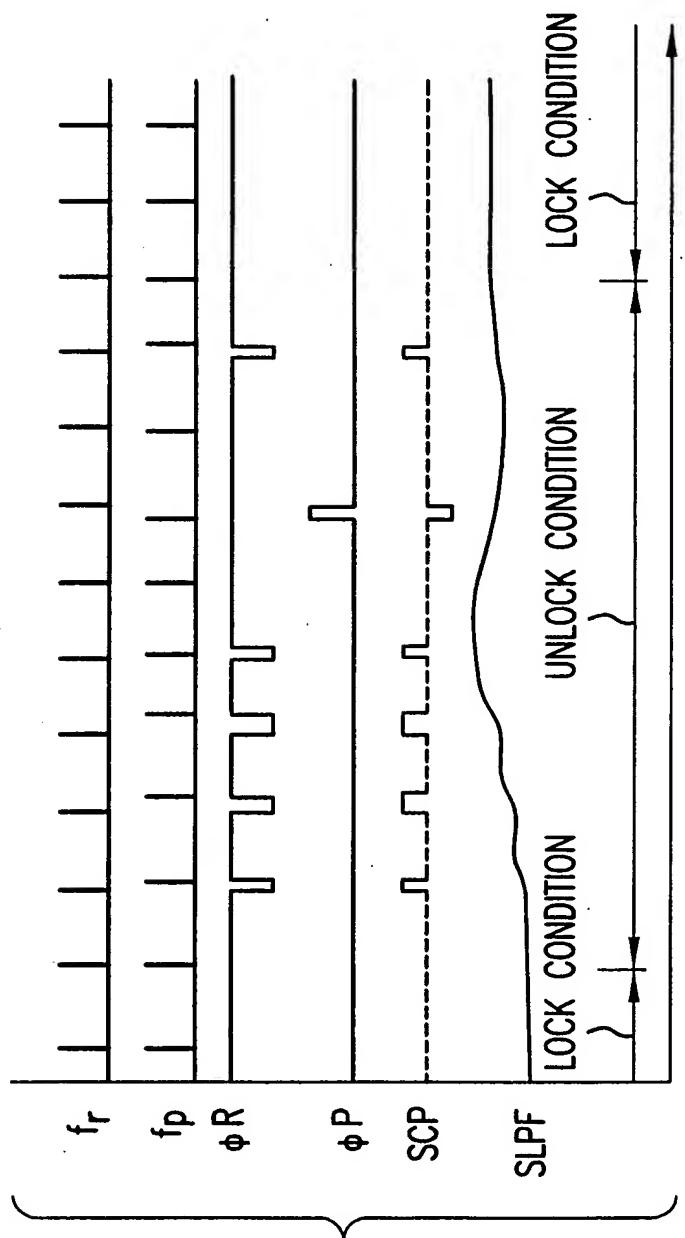


FIG.2



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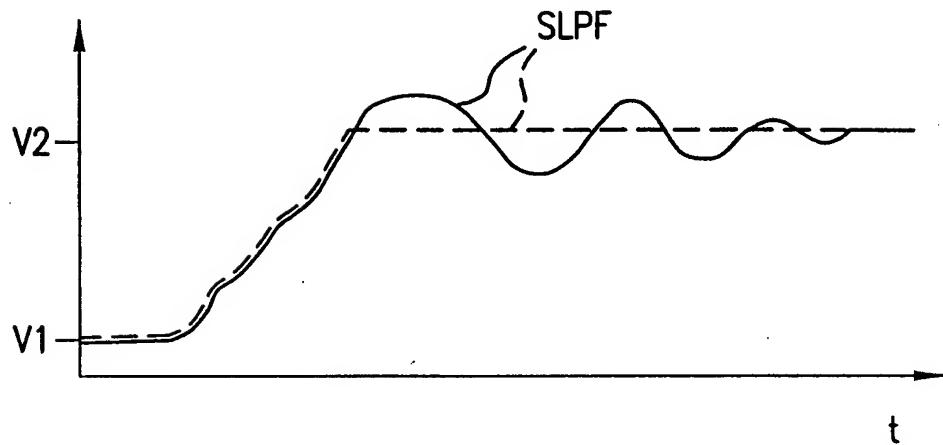


FIG.3

+ VE INPUT

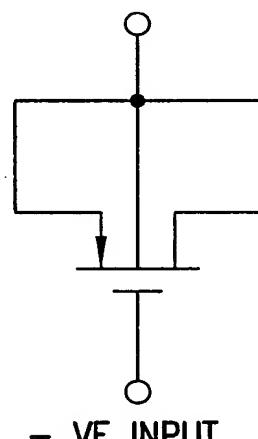


FIG.4

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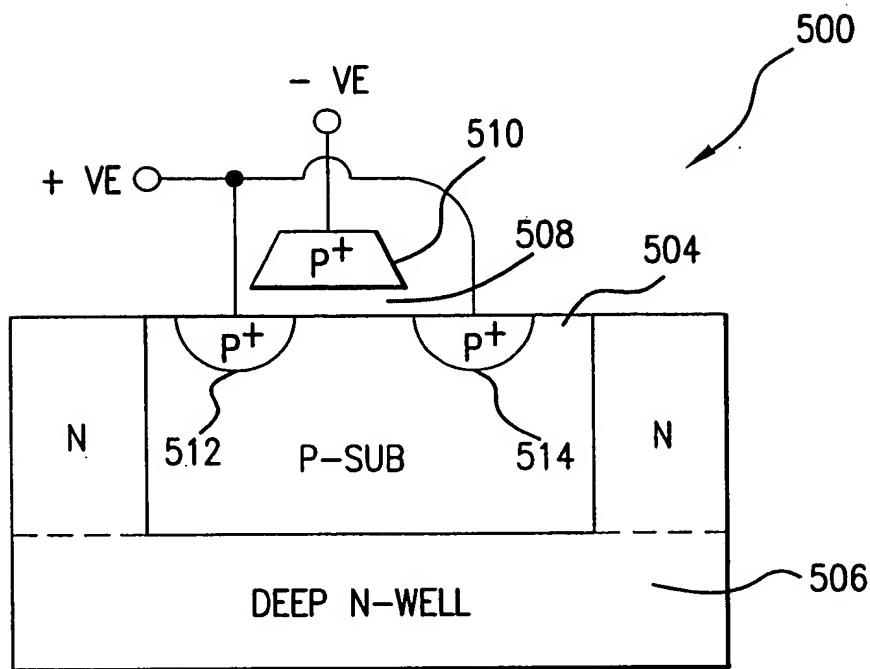


FIG.5

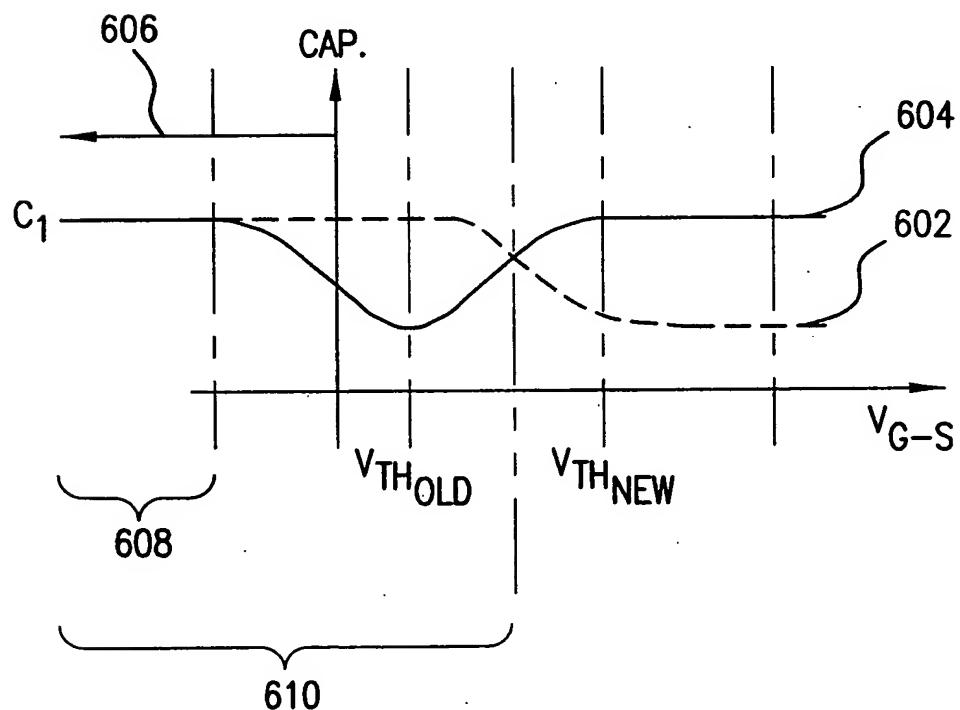


FIG.6